

Notice of References Cited

Application/Control No.

10/082,965

Applicant(s)/Patent Under
Reexamination
IMAI ET AL.

Examiner

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Art Unit

1751

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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	U	Allan et al "High-pressure semiconductor-semimetal transition in TiS ₂ ", Physical Review-B, 1998, 57(9), pp 5106-5109.
	V	de Boer et al, "Titanium ditelluride: Band Structure, photoemission, electrical and magnetic properties", Physical Review-B, 1984, 29(12), pp 6797-6809.
	W	Amara et al, "Thermoelectric Power of TiS ₂ ", Physical Review-B, 1987, 36(12), pp 6415-6419.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.